Diode Semiconductor Device - Page 1 of 1



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| Inclosure Materia | ıl: |
|---------------------|---|
| Ceramic | ··· |
| Overall Length: | |
| 0.260 inches | |
| Terminal Length | |
| 1.000 inches | |
| Overall Diameter | |
| 0.120 inches | |
| Joint Electronic | Device Engineering Council/jedec/case Outline Designation: |
| Do-7 | |
| Mounting Metho | 1: |
| Terminal | |
| Terminal Circle D | Diameter: |
| 0.018 inches | |
| Semiconductor M | faterial: |
| Silicon | |
| Voltage Rating Ir | Volts Per Characteristic: |
| 65.0 breakdown v | roltage, instantaneous |
| Power Rating Pe | |
| 400.0 milliwatts sr | nall-signal input power, common-collector megawatts |
| Capacitance Rati | ng In Picofarads: |
| Between 78.0 and | 86.0 |
| Maximum Operat | ing Tempurature Per Measurement Point: |
| 150.0 degrees cel | sius ambient air |
| Nuclear Hardnes | s Critical Feature: |
| Hardened | |
| Test Data Docum | ent: |
| 80063-a3132211 | drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing |
| etc.; excludes an | v specification, standard or other document that may be referenced in a basic governing drawing) |
| Terminal Type A | nd Quantity: |
| 2 uninsulated wire | lead |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |